## NSN 5961-01-084-0815

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-084-0815 **Inclosure Material:** Glass **Overall Length:** Between 0.140 inches and 0.195 inches **Terminal Length:** Between 0.900 inches and 1.300 inches **Overall Diameter:** Between 0.135 inches and 0.185 inches **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 42.6 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 18.60 amperes source cutoff current universal **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector megahertz **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** 1500w maximum reverse peak pulse power; 80.7v maximum clamping voltage **Precious Material And Location:** 

Terminal surface option silver

**Precious Material:** 

Silver

## **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## **Terminal Type And Quantity:**

2 uninsulated wire lead

## **Specification Data:**

81349-mil-s-19500/516 government specification

Shelf Life:

N/a

**Unit Of Measure:** 

**Demilitarization:** 

No

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